National Semiconductor

July 1998

54ABT241
Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The ABT241 is an octal buffer and line driver with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

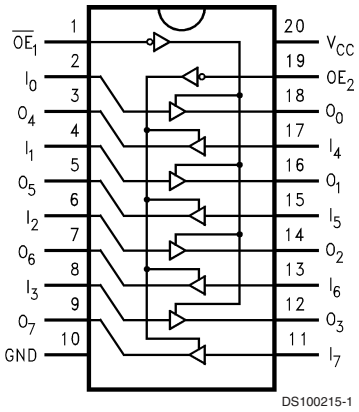
- Non-inverting buffers
- Output sink capability of 48 mA, source capability of 24 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Standard Microcircuit Drawing (SMD) 5962-9322701

Ordering Code

Military	Package Number	Package Description
54ABT241J-QML	J20A	20-Lead Ceramic Dual-In-Line
54ABT241W-QML	W20A	20-Lead Cerpack
54ABT241E-QML	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

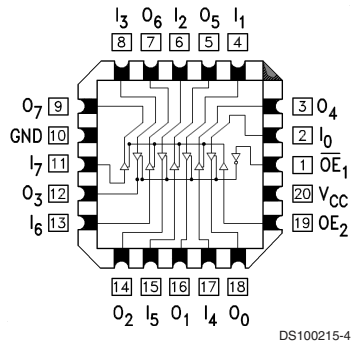
Connection Diagram

Pin Assignment for DIP and Cerpack



DS100215-1

Pin Assignment for LCC



DS100215-4

Pin Names	Description
$\overline{OE}_1$	Output Enable Input (Active Low)
OE_2	Output Enable Input (Active High)
I_0–I_7	Inputs
O_0–O_7	Outputs

$\overline{OE}_1$	I_{0-3}	O_{0-3}	$\overline{OE}_2$	I_{4-7}	O_{4-7}
H	X	Z	L	X	Z
L	H	H	H	H	H
L	L	L	H	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

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Absolute Maximum Ratings (Note 1)

Storage Temperature	−65˚C to +150˚C
Ambient Temperature under Bias	−55˚C to +125˚C
Junction Temperature under Bias	
Ceramic	−55˚C to +175˚C
V_{CC} Pin Potential to	
Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	
(Over Comm Operating Range)	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55˚C to +125˚C
Supply Voltage	
Military	+4.5V to +5.5V
Minimum Input Edge Rate	($\Delta V/\Delta t$)
Data Input	50 mV/ns
Enable Input	20 mV/ns

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		Min	Typ	Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54ABT	2.5			V	Min	I_{OH} = −3 mA
		54ABT	2.0			V	Min	I_{OH} = −24 mA
V_{OL}	Output LOW Voltage	54ABT			0.55	V	Min	I_{OL} = 48 mA
I_{IH}	Input HIGH Current				5	µA	Max	V_{IN} = 2.7V (Note 4)
					5			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	µA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−5	µA	Max	V_{IN} = 0.5V (Note 4)
					−5			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 µA All Other Pins Grounded
I_{OZH}	Output Leakage Current				50	µA	0 − 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−50	µA	0 − 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	µA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	µA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	µA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	µA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs 3-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs 3-STATE			50	µA		Data Input V_I = V_{CC} − 2.1V
								All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs Open
	(Note 4)				0.1	MHz		$\overline{OE}_n$ = GND, (Note 3)
								One Bit Toggling, 50%
								Duty Cycle

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

DC Electrical Characteristics

Symbol	Parameter	Min	Max	Units	V_{CC}	Conditions C_L = 50 pF, R_L = 500Ω
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}		0.67	V	5.0	T_A = 25˚C (Note 5)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}		-1.35	V	5.0	T_A = 25˚C (Note 5)

Note 5: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

AC Electrical Characteristics

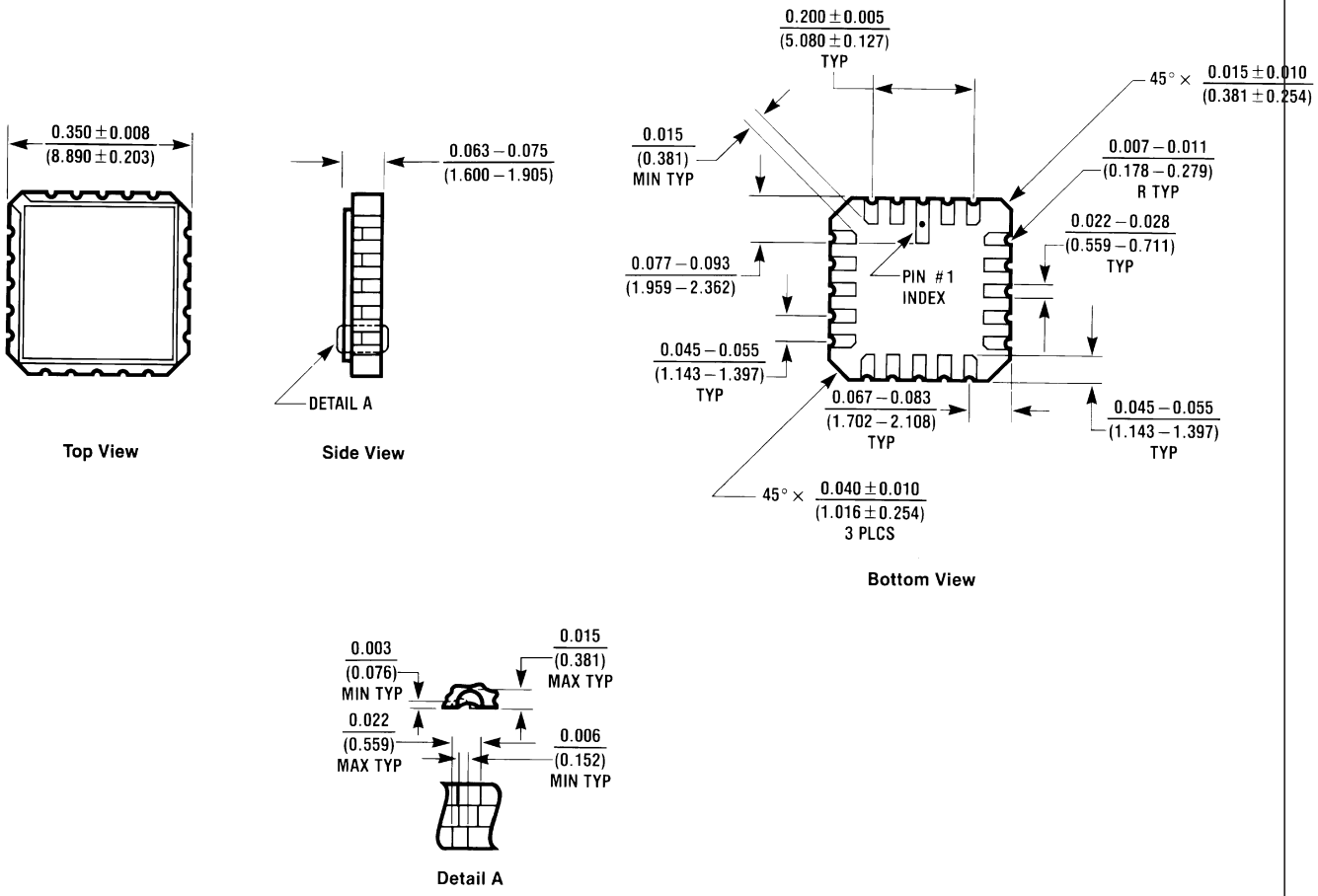
Symbol	Parameter	T_A = –55˚C to +125˚C, V_{CC} = 4.5V–5.5V, C_L = 50 pF		Units
		Min	Max	
t_{PLH}	Propagation Delay	0.8	5.3	ns
t_{PHL}	Data to Outputs	0.8	5.0	
t_{PZH}	Output Enable	1.0	7.0	ns
t_{PZL}	Time	1.0	7.0	
t_{PHZ}	Output Disable	0.8	7.9	ns
t_{PLZ}	Time	0.8	6.2	

Capacitance

Symbol	Parameter	Typ	Units	Conditions T_A = 25˚C
C_{IN}	Input Capacitance	5.0	pF	V_{CC} = 0V
C_{OUT} (Note 6)	Output Capacitance	9.0	pF	V_{CC} = 5.0V

Note 6: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

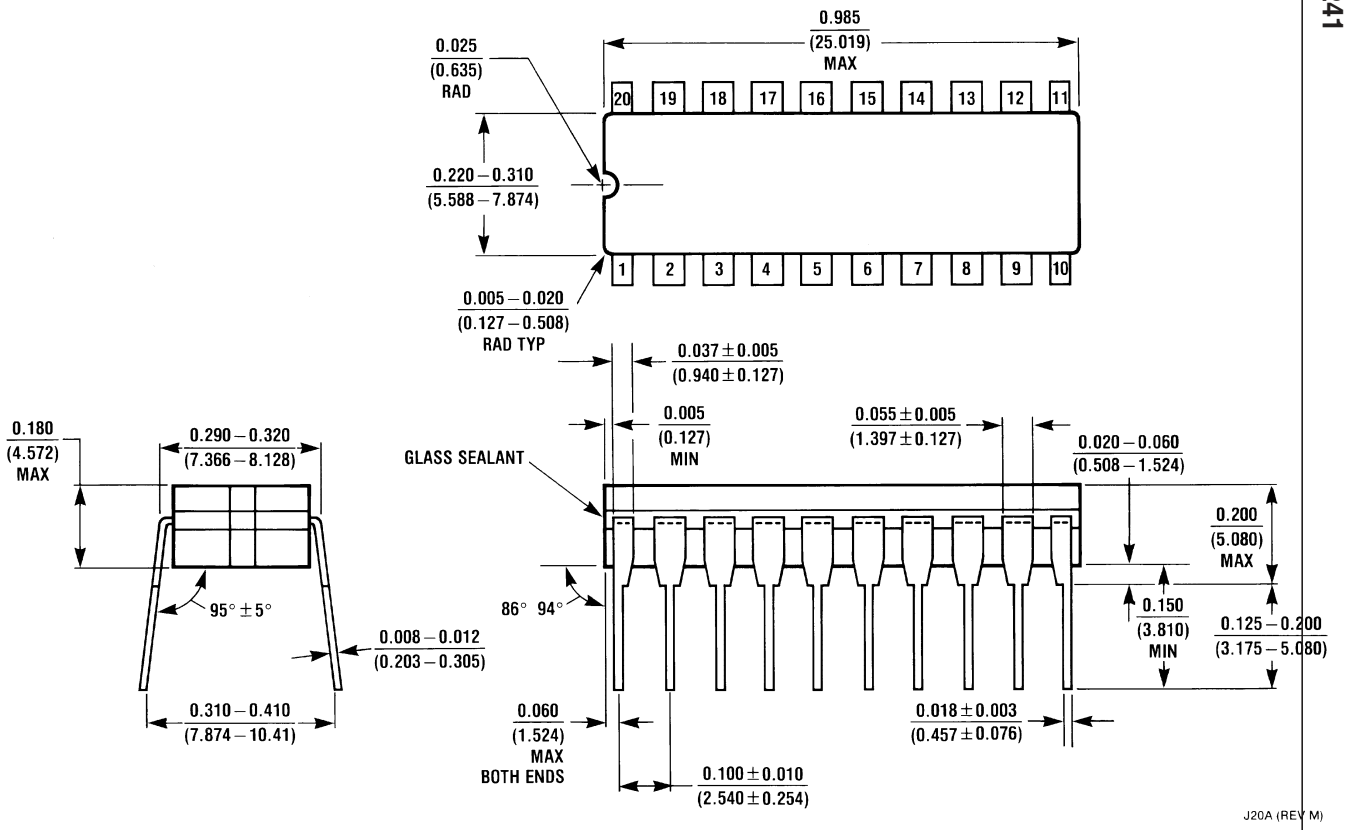
Physical Dimensions inches (millimeters) unless otherwise noted



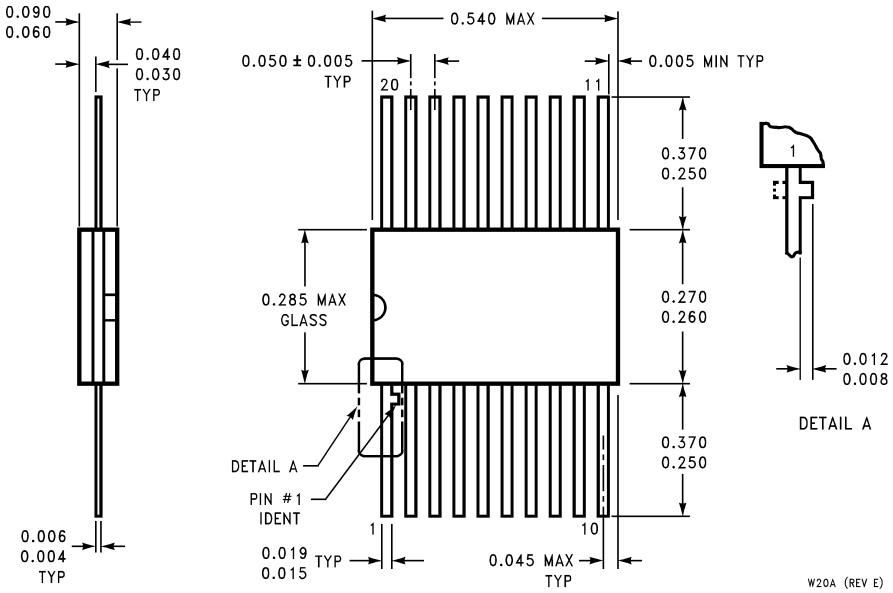
E20A (REV D)

20-Lead Ceramic Leadless Chip Carrier
Package Number E20A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Ceramic Dual-In-Line
Package Number J20A



20-Lead Ceramic Flatpack
Package Number W20A

Notes

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